

Inchange Semiconductor

Product Specification

Silicon NPN Power Transistors

2SD600 2SD600K

DESCRIPTION

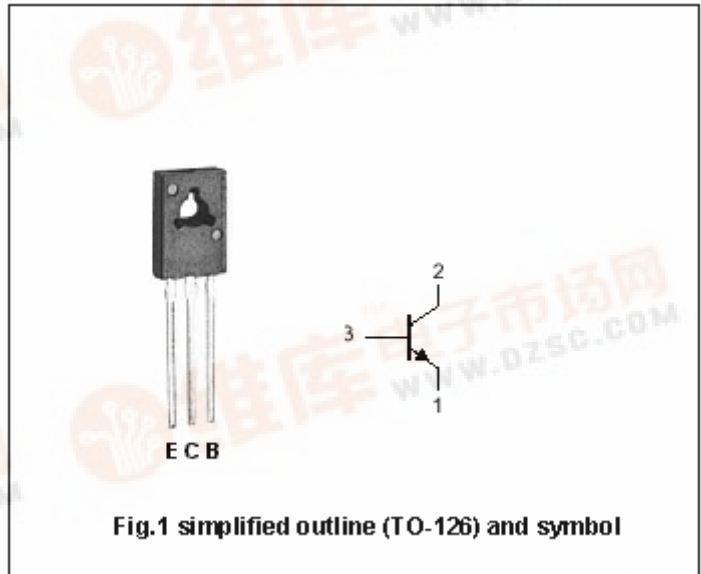
- With TO-126 package
- Complement to type 2SB631/631K
- High breakdown voltage $V_{CE0}100/120V$
- High current 1A
- Low saturation voltage

APPLICATIONS

- For low-frequency power amplifier applications

PINNING

PIN	DESCRIPTION
1	Emitter
2	Collector;connected to mounting base
3	Base



Absolute maximum ratings(Ta=25°C)

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
V_{CBO}	Collector-base voltage	2SD600	100	V
		2SD600K		
V_{CEO}	Collector-emitter voltage	2SD600	100	V
		2SD600K		
V_{EBO}	Emitter-base voltage	Open collector	5	V
I_C	Collector current (DC)		1	A
I_{CM}	Collector current-peak		2	A
P_D	Total power dissipation	$T_a=25^\circ C$	1	W
		$T_c=25^\circ C$	8	
T_j	Junction temperature		150	°C
T_{stg}	Storage temperature		-55~150	°C

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CHARACTERISTICS

T_j=25°C unless otherwise specified

SYMBOL	PARAMETER		CONDITIONS	MIN	TYP.	MAX	UNIT
V _{(BR)CEO}	Collector-emitter breakdown voltage	2SD600	I _C =1mA; R _{BE} =∞	100			V
		2SD600K		120			
V _{(BR)CBO}	Collector-base breakdown voltage	2SD600	I _C =10 μA; I _E =0	100			V
		2SD600K		120			
V _{(BR)EBO}	Emitter-base breakdown voltage		I _E =10 μA; I _C =0	5			V
V _{CEsat}	Collector-emitter saturation voltage		I _C =0.5A; I _B =50mA			0.4	V
V _{BEsat}	Base-emitter saturation voltage		I _C =0.5A; I _B =50mA			1.2	V
I _{CBO}	Collector cut-off current		V _{CB} =50V; I _E =0			1	μA
I _{EBO}	Emitter cut-off current		V _{EB} =4V; I _C =0			1	μA
h _{FE-1}	DC current gain		I _C =50mA; V _{CE} =5V	60		320	
h _{FE-2}	DC current gain		I _C =0.5A; V _{CE} =5V	20			
f _T	Transition frequency		I _C =50mA; V _{CE} =10V		130		MHz
C _{OB}	Collector output capacitance		f=1MHz; V _{CB} =10V		20		pF

Switching times

t _f	Fall time	I _C =500mA; V _{CE} =12V I _{B1} =-I _{B2} =50mA		0.1		μs
t _{off}	Turn-off time			0.5		μs
t _{stg}	Storage time			0.7		μs

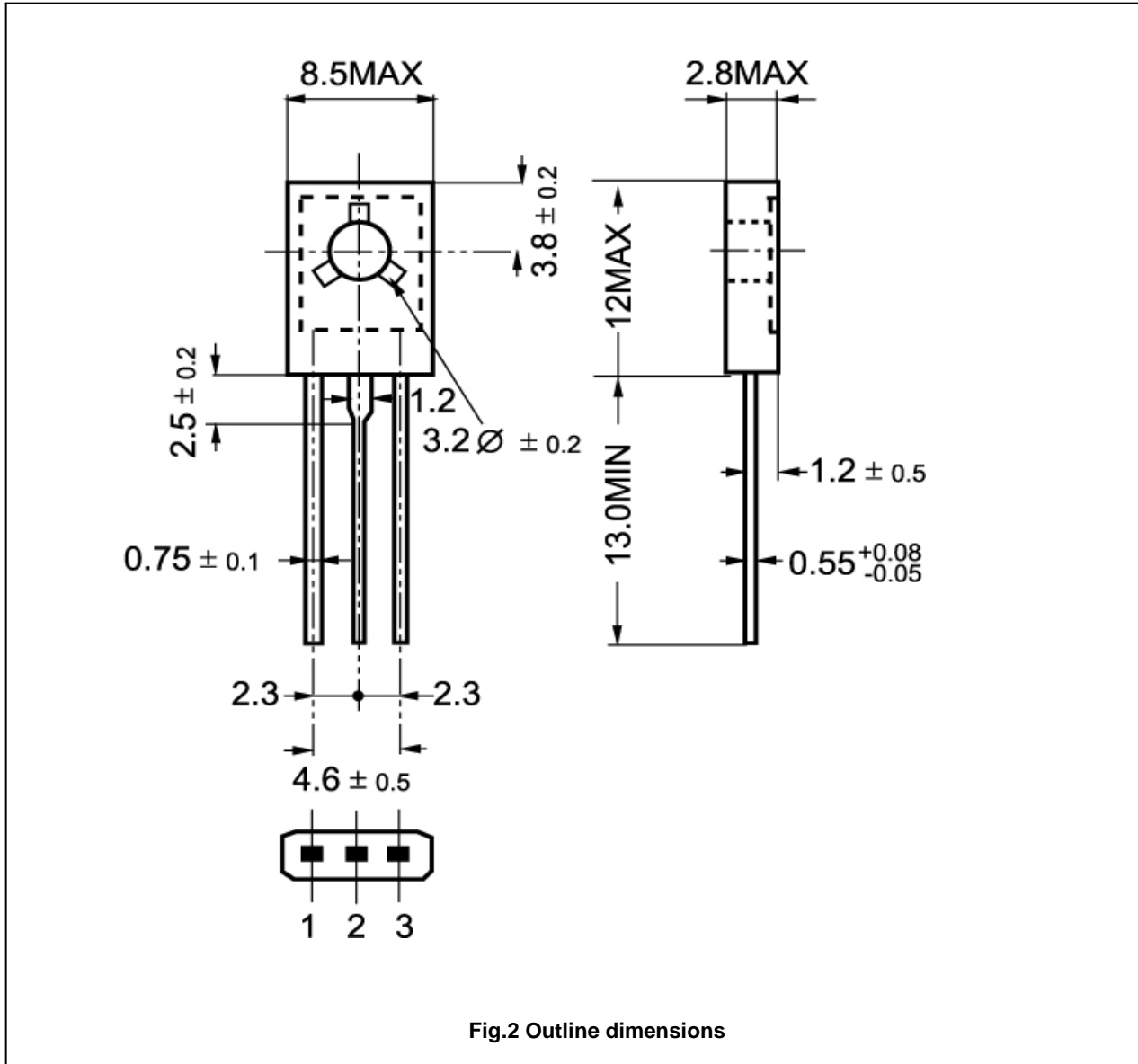
◆ h_{FE-1} Classifications

D	E	F
60-120	100-200	160-320

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PACKAGE OUTLINE



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